# onsemi

# TinyLogic ULP-A Dual Buffer (Open-Drain Output)

# NC7WV07

The NC7WV07 is a dual buffer with open-drain output in tiny footprint packages. The device is designed to operate for  $V_{CC} = 0.9 \text{ V}$  to 3.6 V.

#### Features

- Designed for 0.9 V to 3.6 V  $V_{CC}$  Operation
- 1.6 ns t<sub>PD</sub> at 3.3 V (Typ)
- Inputs/Outputs Over–Voltage Tolerant up to 3.6 V
- I<sub>OFF</sub> Supports Partial Power Down Protection
- Source/Sink 24 mA at 3.3 V
- Available in SC-88 and MicroPak<sup>TM</sup> Packages
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

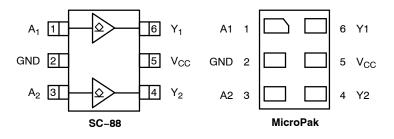


Figure 1. Pinout Diagrams (Top Views)

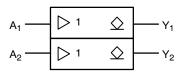
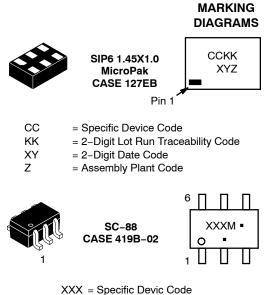


Figure 2. Logic Symbol

#### **PIN ASSIGNMENT**

Pin	Function
1	A1
2	GND
3	A2
4	Y2
5	V <sub>CC</sub>
6	Y1



- M = Date Code\*
- = Pb-Free Package

(Note: Microdot may be in either location) \*Date Code orientation and/or position may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

See detailed ordering, marking and shipping information on page 6 of this data sheet.

#### FUNCTION TABLE

A Input	Y Output				
L	L				
Н	Z				

Z = High Impedance

#### MAXIMUM RATINGS

Symbol	Characteris	stics	Value	Unit	
V <sub>CC</sub>	DC Supply Voltage		-0.5 to +4.3	V	
V <sub>IN</sub>	DC Input Voltage		-0.5 to +4.3	V	
V <sub>OUT</sub>	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 1) Power-Down Mode (V <sub>CC</sub> = 0 V)	-0.5 to V <sub>CC</sub> + 0.5 -0.5 to +4.3 -0.5 to +4.3	V	
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-50	mA	
I <sub>OK</sub>	DC Output Diode Current	-50	mA		
I <sub>OUT</sub>	DC Output Source/Sink Current	±50	mA		
I <sub>CC</sub> or I <sub>GND</sub>	DC Supply Current per Supply Pin or Groun	±50	mA		
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C		
ΤL	Lead Temperature, 1 mm from Case for 10	Seconds	260	°C	
TJ	Junction Temperature Under Bias		+150	°C	
$\theta_{JA}$	Thermal Resistance (Note 2)	SC-88 MicroPak	377 154	°C/W	
PD	Power Dissipation in Still Air	SC-88 MicroPak	332 812	mW	
MSL	Moisture Sensitivity		Level 1	-	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in	-	
$V_{\text{ESD}}$	ESD Withstand Voltage (Note 3)	Human Body Model Charged Device Model	4000 2000	V	
I <sub>Latchup</sub>	Latchup Performance (Note 4)		±100	mA	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
Applicable to devices with outputs that may be tri-stated.
Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow per JESD51-7.
HBM tested to EIA / JESD22-A114-A. CDM tested to JESD22-C101-A. JEDEC recommends that ESD qualification to EIA/JESD22-A115A (Machine Model) be discontinued.

4. Tested to EIA/JESD78 Class II.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Para	Min	Max	Unit	
V <sub>CC</sub>	Positive DC Supply Voltage		0.9	3.6	V
V <sub>IN</sub>	DC Input Voltage	0	3.6	V	
V <sub>OUT</sub>	DC Output Voltage	Active-Mode (High or Low State) Tri-State Mode (Note 5) Power-Down Mode (V <sub>CC</sub> = 0 V)	0 0 0	V <sub>CC</sub> 3.6 3.6	
T <sub>A</sub>	Operating Temperature Range		-40	+85	°C
t <sub>r</sub> , t <sub>f</sub>	Input Transition Rise and Fall Time	$V_{CC}=3.3~V\pm0.3~V$	0	10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 5. Applicable to devices with outputs that may be tri-stated.

#### DC ELECTRICAL CHARACTERISTICS

				T	T <sub>A</sub> = 25°C			C to +85°C	
Symbol	Parameter	Condition	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Max	Unit
V <sub>IH</sub>	High-Level Input		0.9	-	0.5	-	-	-	V
	Voltage		1.1 to 1.3	$0.65 \times V_{CC}$	-	-	$0.65 \times V_{CC}$	-	
			1.4 to 1.6	0.65 x V <sub>CC</sub>	-	-	$0.65 \times V_{CC}$	-	
			1.65 to 1.95	$0.65 \times V_{CC}$	-	-	0.65 x V <sub>CC</sub>	-	
			2.3 to <2.7	1.6	-	-	1.6	_	
			2.7 to 3.6	2.0	-	-	2.0	_	
VIL	Low-Level Input		0.9	-	0.5	-	-	-	V
	Voltage		1.1 to 1.3	-	-	0.35 x V <sub>CC</sub>	-	$0.35 \times V_{CC}$	
			1.4 to 1.6	-	-	$0.35 \times V_{CC}$	-	$0.35 \times V_{CC}$	
			1.65 to 1.95	-	-	$0.35 \times V_{CC}$	-	$0.35 \times V_{CC}$	
			2.3 to <2.7	-	-	0.7	-	0.7	
			2.7 to 3.6	-	-	0.8	-	0.8	
V <sub>OL</sub>	Low-Level Output Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$							V
		I <sub>OL</sub> = 100 μA	0.9	-	0.1	-	-	-	
			1.1 to 1.3	-	-	0.1	-	0.1	
			1.4 to 1.6	-	-	0.1	-	0.1	
			1.65 to 1.95	-	-	0.2	-	0.2	
			2.3 to < 2.7	-	-	0.2	-	0.2	
			2.7 to 3.6	-	-	0.2	-	0.2	
		I <sub>OL</sub> = 2 mA	1.1 o 1.3	-	-	$0.25 \times V_{CC}$	-	$0.25 \times V_{CC}$	
		I <sub>OL</sub> = 4 mA	1.4 to 1.6	-	-	$0.25 \times V_{CC}$	-	$0.25 \times V_{CC}$	
		I <sub>OL</sub> = 6 mA	1.65 to 1.95	-	-	0.3	-	0.3	
		I <sub>OL</sub> = 12 mA	2.3 to <2.7	-	-	0.4	-	0.4	
			2.7 to 3.6	-	-	0.4	-	0.4	
		I <sub>OL</sub> = 18 mA	2.3 to <2.7	-	-	0.6	-	0.6	
			2.7 to 3.6	-	-	0.4	-	0.4	
		I <sub>OL</sub> = 24 mA	2.7 to 3.6	-	-	0.55	-	0.55	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 0 V to 3.6 V	0.9 to 3.6	-	-	±0.1	-	±0.5	μA

#### DC ELECTRICAL CHARACTERISTICS (continued)

				T <sub>A</sub> = 25°C		T <sub>A</sub> = -40°C to +85°C			
Symbol	Parameter	Condition	V <sub>CC</sub> (V)	Min	Тур	Мах	Min	Max	Unit
I <sub>OFF</sub>	Power Off Leakage Current	$\begin{array}{l} V_{IN} = 0 \ V \ to \ 3.6 \ V \ or \\ V_{OUT} = 0 \ V \ to \ 3.6 \ V \end{array}$	0	-	-	0.5	-	0.5	μA
I <sub>CC</sub>	Quiescent Supply Current	$V_{IN} = V_{CC}$ or GND	0.9 to 3.6	-	-	0.9	-	0.9	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

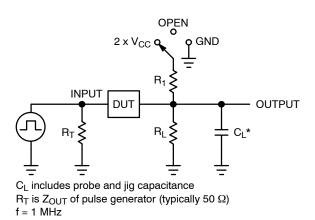
#### AC ELECTRICAL CHARACTERISTICS

				T <sub>A</sub> = 25°C		T <sub>A</sub> = -40°C to +85°C					
Symbol	Parameter	Condition	V <sub>CC</sub> (V)	Min	Тур	Max	Min	Мах	Unit		
t <sub>PZL</sub> , Propagation Delay, t <sub>PLZ</sub> A to Y (Figures 3 and 4)	$\begin{array}{l} R1=R_{L}=1\ M\Omega,\\ C_{L}=15\ pF \end{array}$	0.9	-	11.8	-	-	-	ns			
		$\begin{array}{l} R1=R_{L}=2\ k\Omega,\\ C_{L}=15\ pF \end{array}$	$R1 = R_L = 2 k\Omega$ ,	$R1 = R_L = 2 k\Omega$ ,	1.1 to 1.3	1	5.1	15.0	-	18.6	
			1.4 to 1.6	-	3.6	8.7	-	9.7			
		R1 = R <sub>L</sub> = 500 Ω, C <sub>L</sub> = 30 pF	1.65 to 1.95	-	2.4	6.0	-	6.8			
		C <sub>L</sub> = 30 p⊢	2.3 to 2.7	-	1.9	3.6	-	4.7			
			2.7 to 3.6	_	1.6	3.3	_	4.0			

#### **CAPACITIVE CHARACTERISTICS**

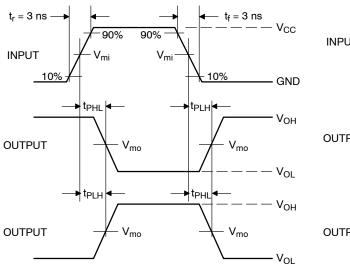
Symbol	Parameter	Test Condition	Typical (T <sub>A</sub> = 25°C)	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = 0 V	2.0	pF
C <sub>OUT</sub>	Output Capacitance	V <sub>CC</sub> = 0 V	6.5	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	f = 10 MHz, V_{CC} = 0.9 to 3.6 V, V <sub>IN</sub> = 0 V or V <sub>CC</sub>	10.0	pF

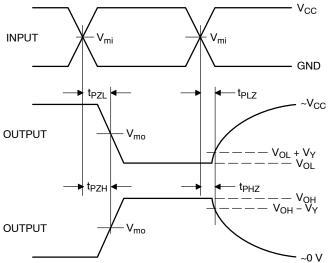
6.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no-load dynamic power consumption:  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .



Test	Switch Position
t <sub>PLH</sub> / t <sub>PHL</sub>	Open
t <sub>PLZ</sub> / t <sub>PZL</sub>	6 V @ Vcc = 3.0–3.6 V; 2 x Vcc @ Vcc = 0.9–2.7 V
t <sub>PHZ</sub> / t <sub>PZH</sub>	GND

Figure 3. Test Circuit





V <sub>CC</sub> , V	V <sub>mi</sub> , V	V <sub>mo</sub> , V	V <sub>Y</sub> , V
0.9	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	0.1
1.1 to 1.3	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	0.1
1.4 to 1.6	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	0.1
1.65 to 1.95	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	0.15
2.3 to 2.7	V <sub>CC</sub> / 2	V <sub>CC</sub> / 2	0.15
3.0 to 3.6	1.5	1.5	0.3

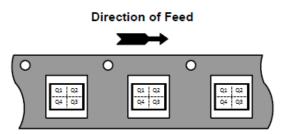
Figure 4. Switching Waveforms

#### **ORDERING INFORMATION**

Device	Package	Marking	Pin 1 Orientation (See below)	Shipping <sup>†</sup>
NC7WV07P6X	SC-88	SC-88 V07		3000 / Tape & Reel
NC7WV07L6X	MicroPak	BC	Q4	5000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

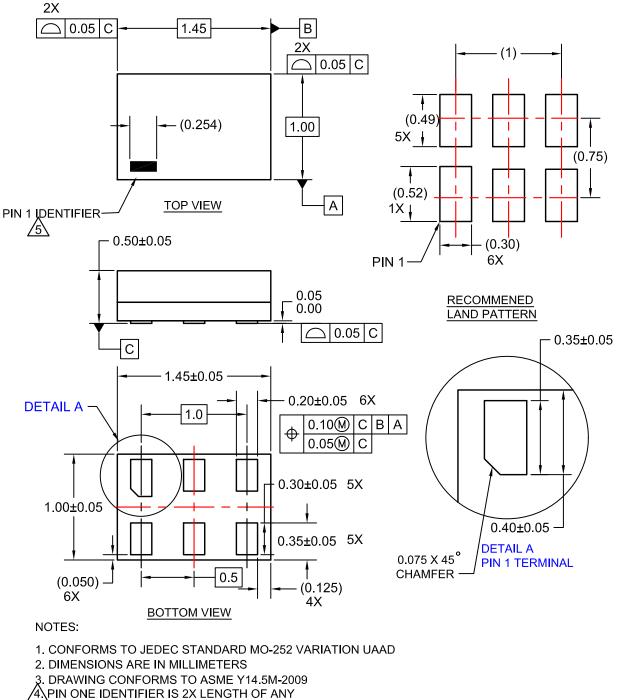
#### Pin 1 Orientation in Tape and Reel



MicroPak is a trademark of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries.

#### PACKAGE DIMENSIONS

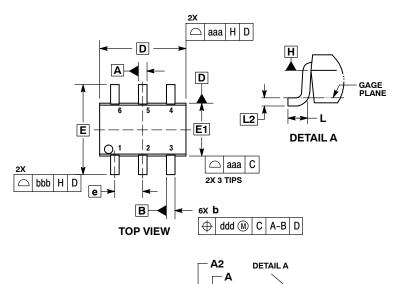
SIP6 1.45X1.0 CASE 127EB ISSUE O



OTHER LINE IN THE MARK CODE LAYOUT.

#### PACKAGE DIMENSIONS

SC-88/SC70-6/SOT-363 CASE 419B-02 **ISSUE Y** 



NOTES:

С

**END VIEW** 

- NOTES:
   DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
   CONTROLLING DIMENSION: MILLIMETERS.
   DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRU-SIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER END.
   DIMENSIONS D AND E1 AT THE OUTERMOST EXTREMES OF THE PLASTIC BODY AND DATUM H.
   DATUMS A AND B ARE DETERMINED AT DATUM H.
   DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP.
   DIMENSION D ODES NOT INCLUDE DAMBAR PROTRUSION
- LEAD BETWEEN 0.08 AND 0.15 FROM THE TIP. DIMENSION & DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 TOTAL IN EXCESS OF DIMENSION & AT MAXIMUM MATERIAL CONDI-TION. THE DAMBAR CANNOT BE LOCATED ON THE LOWER DADI IS OF THE FOOT 7. RADIUS OF THE FOOT.

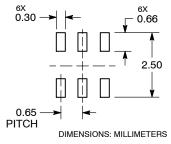
	MILLIMETERS			INCHES				
DIM	MIN	NOM	MAX	MIN	NOM	MAX		
Α			1.10			0.043		
A1	0.00		0.10	0.000		0.004		
A2	0.70	0.90	1.00	0.027	0.035	0.039		
b	0.15	0.20	0.25	0.006	0.008	0.010		
С	0.08	0.15	0.22	0.003	0.006	0.009		
D	1.80	2.00	2.20	0.070	0.078	0.086		
E	2.00	2.10	2.20	0.078	0.082	0.086		
E1	1.15	1.25	1.35	0.045	0.049	0.053		
е	(	0.65 BS	С	0.026 BSC				
L	0.26	0.36	0.46	0.010	0.014	0.018		
L2		0.15 BS	SC	0.006 BSC				
aaa	0.15				0.006			
bbb	0.30			0.012				
CCC	0.10			0.004				
ddd		0.10			0.004			

#### RECOMMENDED **SOLDERING FOOTPRINT\***

SIDE VIEW

A1

ex □ ccc C



\*For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **STYLES ON PAGE 2**

#### SC-88/SC70-6/SOT-363 CASE 419B-02 ISSUE Y

STYLE 1: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	STYLE 2: CANCELLED	STYLE 3: CANCELLED	STYLE 4: PIN 1. CATHODE 2. CATHODE 3. COLLECTOR 4. EMITTER 5. BASE 6. ANODE	STYLE 5: PIN 1. ANODE 2. ANODE 3. COLLECTOR 4. EMITTER 5. BASE 6. CATHODE	STYLE 6: PIN 1. ANODE 2 2. N/C 3. CATHODE 1 4. ANODE 1 5. N/C 6. CATHODE 2
STYLE 7: PIN 1. SOURCE 2 2. DRAIN 2 3. GATE 1 4. SOURCE 1 5. DRAIN 1 6. GATE 2	STYLE 8: CANCELLED	STYLE 9: PIN 1. EMITTER 2 2. EMITTER 1 3. COLLECTOR 1 4. BASE 1 5. BASE 2 6. COLLECTOR 2	STYLE 10: PIN 1. SOURCE 2 2. SOURCE 1 3. GATE 1 4. DRAIN 1 5. DRAIN 2 6. GATE 2	STYLE 11: PIN 1. CATHODE 2 2. CATHODE 2 3. ANODE 1 4. CATHODE 1 5. CATHODE 1 6. ANODE 2	STYLE 12: PIN 1. ANODE 2 2. ANODE 2 3. CATHODE 1 4. ANODE 1 5. ANODE 1 6. CATHODE 2
STYLE 13:	STYLE 14:	STYLE 15:	STYLE 16:	STYLE 17:	STYLE 18:
PIN 1. ANODE	PIN 1. VREF	PIN 1. ANODE 1	PIN 1. BASE 1	PIN 1. BASE 1	PIN 1. VIN1
2. N/C	2. GND	2. ANODE 2	2. EMITTER 2	2. EMITTER 1	2. VCC
3. COLLECTOR	3. GND	3. ANODE 3	3. COLLECTOR 2	3. COLLECTOR 2	3. VOUT2
4. EMITTER	4. IOUT	4. CATHODE 3	4. BASE 2	4. BASE 2	4. VIN2
5. BASE	5. VEN	5. CATHODE 2	5. EMITTER 1	5. EMITTER 2	5. GND
6. CATHODE	6. VCC	6. CATHODE 1	6. COLLECTOR 1	6. COLLECTOR 1	6. VOUT1
STYLE 19:	STYLE 20:	STYLE 21:	STYLE 22:	STYLE 23:	STYLE 24:
PIN 1. I OUT	PIN 1. COLLECTOR	PIN 1. ANODE 1	PIN 1. D1 (i)	PIN 1. Vn	PIN 1. CATHODE
2. GND	2. COLLECTOR	2. N/C	2. GND	2. CH1	2. ANODE
3. GND	3. BASE	3. ANODE 2	3. D2 (i)	3. Vp	3. CATHODE
4. V CC	4. EMITTER	4. CATHODE 2	4. D2 (c)	4. N/C	4. CATHODE
5. V EN	5. COLLECTOR	5. N/C	5. VBUS	5. CH2	5. CATHODE
6. V REF	6. COLLECTOR	6. CATHODE 1	6. D1 (c)	6. N/C	6. CATHODE
STYLE 25:	STYLE 26:	STYLE 27:	STYLE 28:	STYLE 29:	STYLE 30:
PIN 1. BASE 1	PIN 1. SOURCE 1	PIN 1. BASE 2	PIN 1. DRAIN	PIN 1. ANODE	PIN 1. SOURCE 1
2. CATHODE	2. GATE 1	2. BASE 1	2. DRAIN	2. ANODE	2. DRAIN 2
3. COLLECTOR 2	3. DRAIN 2	3. COLLECTOR 1	3. GATE	3. COLLECTOR	3. DRAIN 2
4. BASE 2	4. SOURCE 2	4. EMITTER 1	4. SOURCE	4. EMITTER	4. SOURCE 2
5. EMITTER	5. GATE 2	5. EMITTER 2	5. DRAIN	5. BASE/ANODE	5. GATE 1
6. COLLECTOR 1	6. DRAIN 1	6. COLLECTOR 2	6. DRAIN	6. CATHODE	6. DRAIN 1

Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment.

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